



SS52C THRU SS5200C

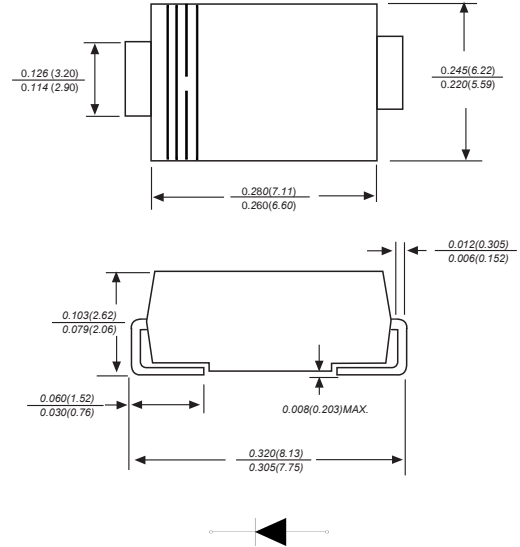
Reverse Voltage - 20 to 200 Volts Forward Current - 5.0 Ampere

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250 °C/10 seconds at terminals

DO-214AB/SMC **RoHS COMPLIANT**



Dimensions in inches and (millimeters)

Mechanical Data

Case: JEDEC DO-214AB/SMC molded plastic body
 Terminals: Solderable per MIL-STD-750, Method 2026
 Polarity: Color band denotes cathode end Mounting
 Position: Any
 Weight: 0.003 ounce, 0.095 grams

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	SS52C	SS53C	SS54C	SS55C	SS56C	SS58C	SS510C	SS5150C	SS5200C	UNITS
		MDD SS52C	MDD SS53C	MDD SS54C	MDD SS55C	MDD SS56C	MDD SS58C	MDD SS510C	MDD SS5150C	MDD SS5200C	
Maximum repetitive peak reverse voltage	V _{RMM}	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current at TL (see fig.1)	I _(AV)	5.0									A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	175						150			A
Maximum instantaneous forward voltage at 5.0A	V _F	0.55			0.70			0.85			V
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =125°C	I _R	1.0						50			mA
Typical junction capacitance (NOTE 1)	C _J	600			400						pF
Typical thermal resistance (NOTE 2)	R _{θJA}	35.0									°C/W
Operating junction temperature range	T _J	-55 to +150									°C
Storage temperature range	T _{STG}	-55 to +150									°C

Note: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 2.0x2.0" (5.0x5.0cm) copper pad areas.
 3. The typical data above is for reference only.



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Typical Characteristics

Fig.1 Forward Current Derating Curve

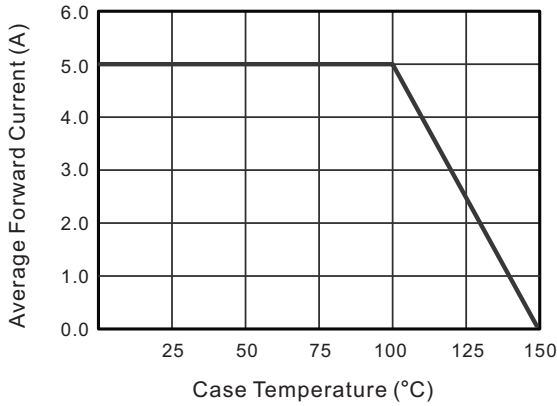


Fig.2 Typical Reverse Characteristics

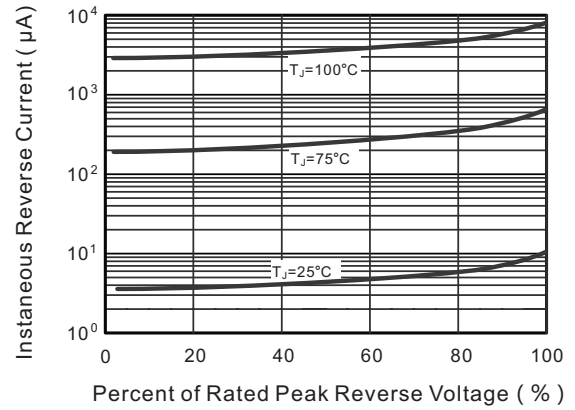


Fig.3 Typical Forward Characteristic

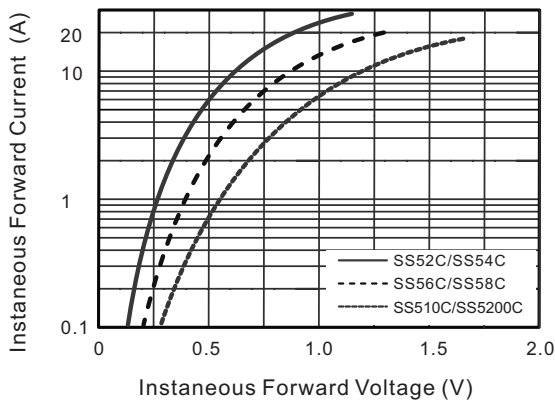


Fig.4 Typical Junction Capacitance

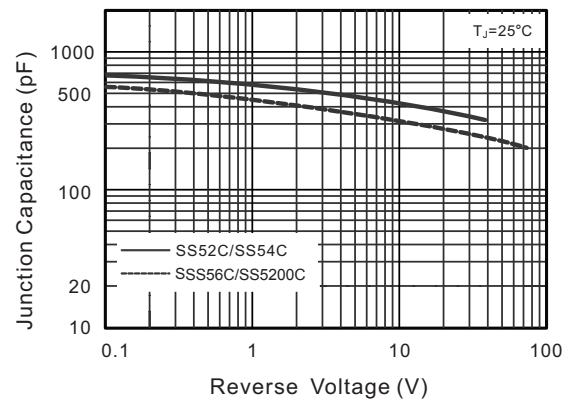


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

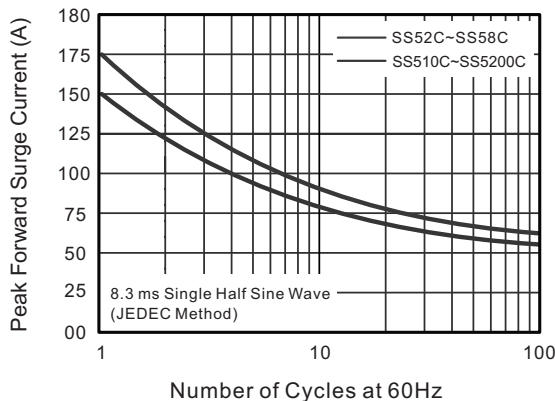
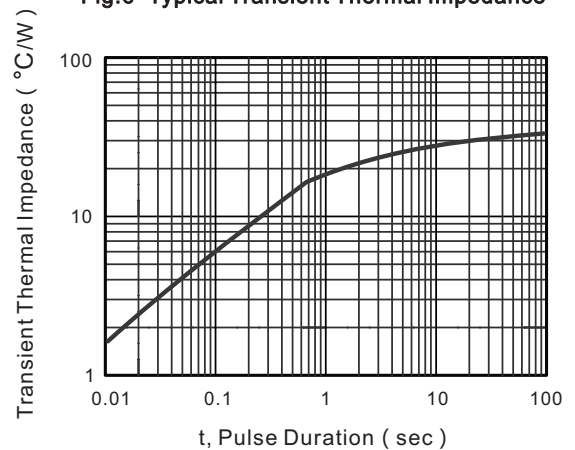


Fig.6- Typical Transient Thermal Impedance



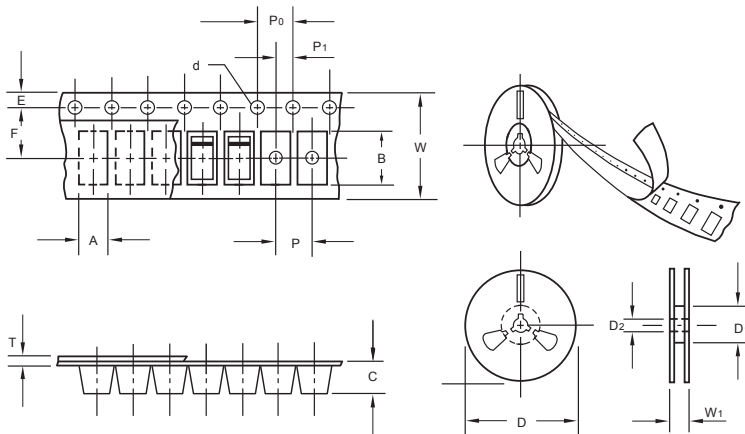
The curve above is for reference only.



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Packing information



unit:mm

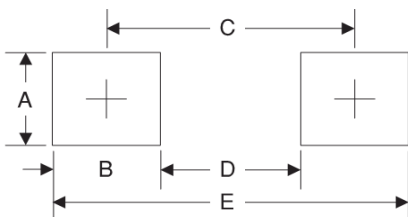
Item	Symbol	Tolerance	SMC
Carrier width	A	0.1	6.15
Carrier length	B	0.1	8.41
Carrier depth	C	0.1	2.42
Sprocket hole	d	0.05	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D ₁	min	50.00
Feed hole diameter	D ₂	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	7.50
Punch hole pitch	P	0.1	8.00
Sprocket hole pitch	P ₀	0.1	4.00
Embossment center	P ₁	0.1	2.00
Overall tape thickness	T	0.1	0.25
Tape width	W	0.3	16.00
Reel width	W ₁	1.0	16.50

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (mm)	BOX (pcs)	INNER BOX (mm)	REEL DIA. (mm)	CARTON SIZE (mm)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMC	13"	3,000	4.0	6000	190*190*41	330	365*365*340	42000	14.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	4.3	0.170
B	4.1	0.160
C	7.9	0.311
D	3.8	0.150
E	12	0.472

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